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PS2514-1,PS2514L-1

Data Sheet

R08DS0012EJ0100 Rev.1.00 Mar 19, 2012

HIGH-SPEED SWITCHING/HIGH ISOLATION VOLTAGE PHOTOCOUPLER SERIES

DESCRIPTION

The PS2514-1 and PS2514L-1 are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor, enabling relatively high switching speed with high load resistor of several $k\Omega$.

The PS2514-1 is in a plastic DIP (Dual In-line Package) and the PS2514L-1 is lead bending type (Gull-wing) for surface mount.

FEATURES

- High isolation voltage (BV = 5 000 Vr.m.s.)
- High collector to emitter voltage (VcEo = 40 V)
- · Guaranteed maximum switching speed

(toff \leq 25 μ s @ IF = 5 mA, Vcc = 5 V, RL = 5 k Ω)

• High-speed switching (ton = 15 μ s TYP. @ IF = 5 mA, Vcc = 5 V, RL = 5 k Ω) (toff = 15 μ s TYP. @ IF = 5 mA, Vcc = 5 V, RL = 5 k Ω)

• Embossed tape product: PS2514L-1-F3: 2 000 pcs/reel

· Pb-Free product

<R> · Safety standards

<R>

· UL approved: No. E72422

CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)

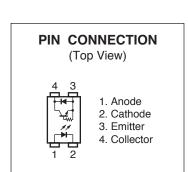
CQC approved: CQC11001056759/CQC11001056758

CQC11001056865/CQC11001057073

DIN EN60747-5-2 (VDE0884 Part2) approved: No. 40008862 (Option)

APPLICATIONS

- · Power supply
- · FA equipment
- · Electronic electricity meter

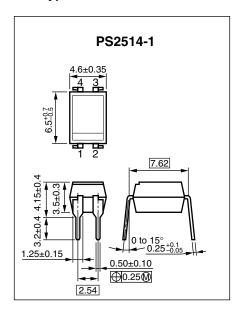


The mark <R> shows major revised points.

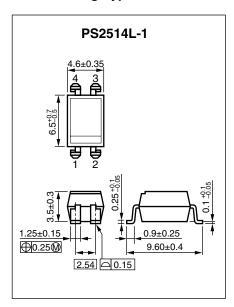
The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

PACKAGE DIMENSIONS (UNIT: mm)

DIP Type



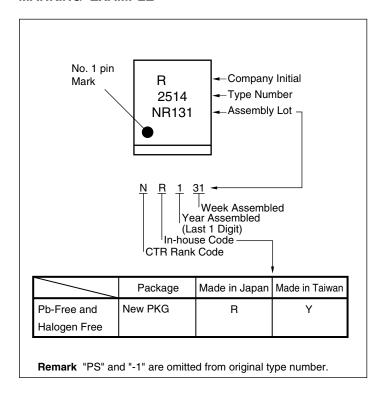
Lead Bending Type



PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	7 mm
Outer Creepage Distance	7 mm
Inner Creepage Distance	4 mm
Isolation Thickness	0.3 mm

<R> MARKING EXAMPLE



<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification etc.	Packing Style	Safety Standard Approval	Application Part Number ^{*1}
PS2514-1	PS2514-1Y-A	Pb-Free and	Magazine case 100 pcs	Standard products	PS2514-1
PS2514L-1	PS2514L-1Y-A	Halogen Free		(UL, CSA, CQC	PS2514L-1
PS2514L-1-F3	PS2514L-1Y-F3-A		Embossed Tape 2 000 pcs/reel	approved)	
PS2514-1-V	PS2514-1Y-V-A		Magazine case 100 pcs	DIN EN60747-5-2	PS2514-1
PS2514L-1-V	PS2514L-1Y-V-A			(VDE0884 Part2)	PS2514L-1
PS2514L-1-V-F3	PS2514L-1Y-V-F3-A		Embossed Tape 2 000 pcs/reel	approved	
				(Option)	

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Reverse Voltage	VR	6	V
	Forward Current (DC)	lF	30	mA
	Power Dissipation Derating	⊿P₀/°C	1.5	mW/°C
	Power Dissipation	Po	150	mW
	Peak Forward Current ¹¹	IFP	0.5	Α
Transistor	Collector to Emitter Voltage	VCEO	40	V
	Emitter to Collector Voltage	VECO	0.6	V
	Collector Current	lc	20	mA
	Power Dissipation Derating	⊿Pc/°C	1.5	mW/°C
Power Dissipation		Pc	150	mW
Isolation Voltage ^{*2}		BV	5 000	Vr.m.s.
Operating A	Operating Ambient Temperature		-55 to +100	°C
Storage Temperature		T _{stg}	-55 to +150	°C

^{*1} PW = 100 μ s, Duty Cycle = 1%

RECOMMENDED OPERATING CONDITIONS

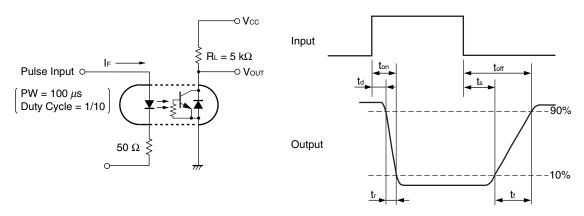
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Input Current	lF	5	6	7	mA

^{*2} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

ELECTRICAL CHARACTERISTICS (TA = 25°C)

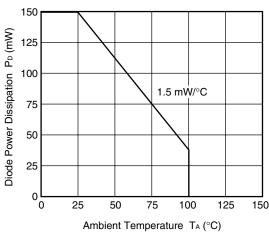
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	I _F = 5 mA		1.1	1.3	V
	Reverse Current	lR	V _R = 5 V			5	μΑ
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		10		pF
Transistor	Collector to Emitter Dark Current	ICEO	VcE = 40 V, IF = 0 mA			100	nA
Coupled	Current Transfer Ratio	CTR	IF = 5 mA, VcE = 5 V	50	125	200	%
	Collector Saturation Voltage	VCE (sat)	IF = 5 mA, Ic = 1 mA			0.35	V
	Isolation Resistance	Ri-o	Vi-o = 1.0 kVDC	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.5		pF
	Turn-on Time*1	ton	V cc = 5 V , I F = 5 m A, R L = 5 $k\Omega$		15	25	μs
	Turn-off Time ^{*1}	t off			15	25	

*1 Test circuit for switching time

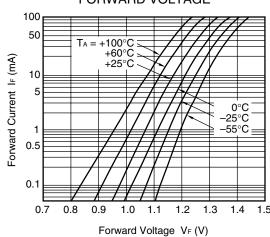


<R> TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)

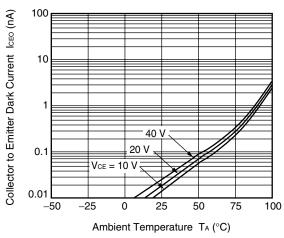
DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



FORWARD CURRENT vs. FORWARD VOLTAGE

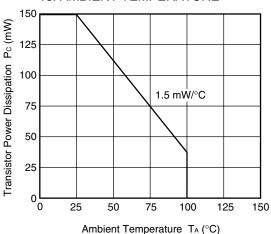


COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

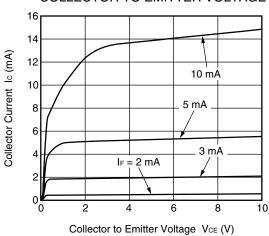


Remark The graphs indicate nominal characteristics.

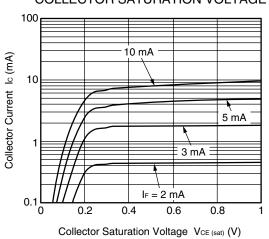
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



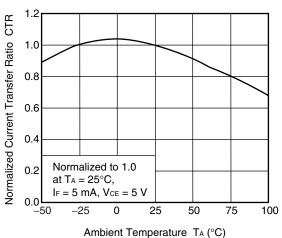
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



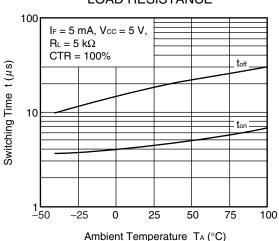
COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



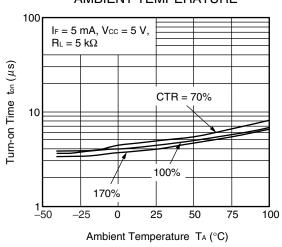
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



SWITCHING TIME vs. LOAD RESISTANCE

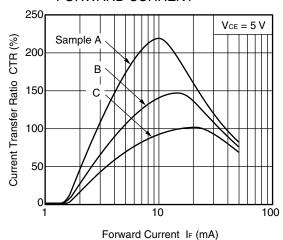


TURN-ON TIME vs. AMBIENT TEMPERATURE

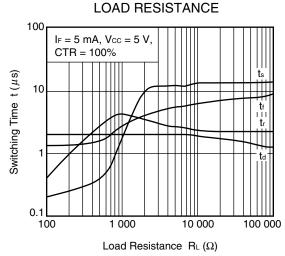


Remark The graphs indicate nominal characteristics.

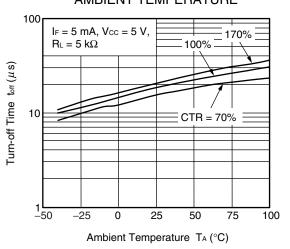
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



SWITCHING TIME vs.

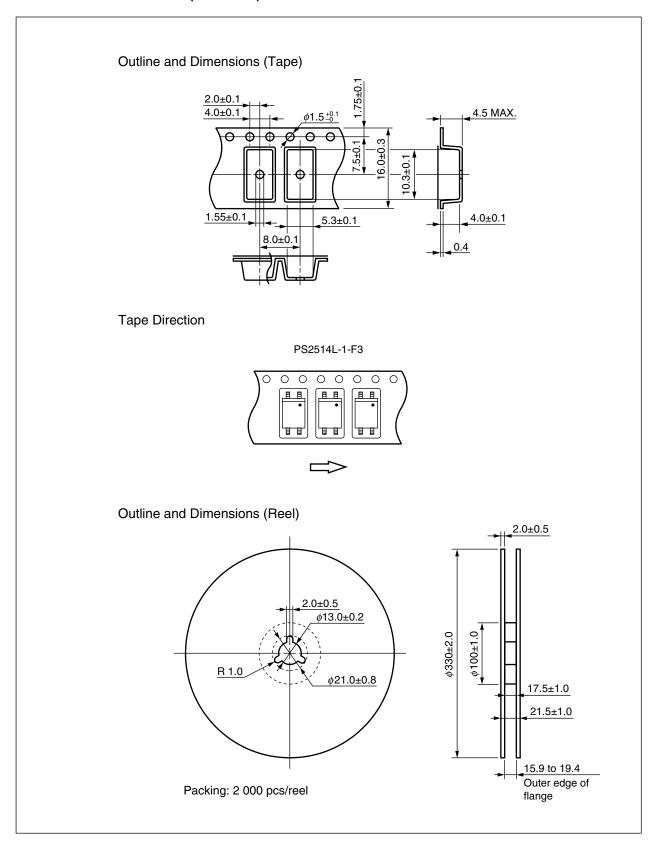


TURN-OFF TIME vs. AMBIENT TEMPERATURE

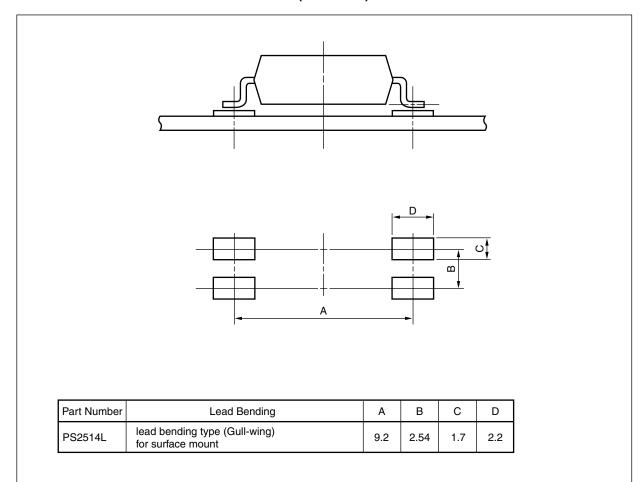


Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)



<R> RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



<R> NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature 260°C or below (package surface temperature)

Time of peak reflow temperature
 Time of temperature higher than 220°C
 50 seconds or less
 60 seconds or less

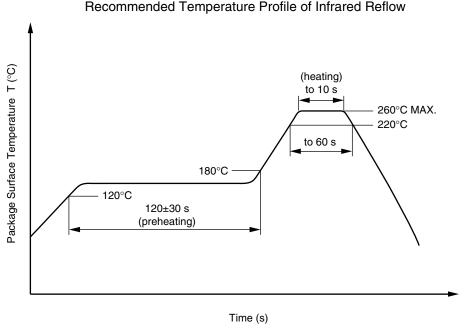
• Time to preheat temperature from 120 to 180°C $120 \pm 30 \text{ s}$

Number of reflows ThreeFlux Rosin

maximum chlorine content of 0.2 Wt% is recommended.)

Rosin flux containing small amount of chlorine (The flux with a

amandad Tamparatura Drofila of Infrared Daflaw



(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

• Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content

of 0.2 Wt% is recommended.)

(3) Soldering by soldering iron

Peak temperature (lead part temperature)
 Time (each pins)
 350°C or below
 3 seconds or less

Flux
 Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead.

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.



2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between correctoremitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.



<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.5 \times U_{\text{IORM}}, P_{\text{d}} < 5 \text{pC}$	UIORM Upr	890 1 335	V _{peak} V _{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr}=1.875\times U_{IORM},\ P_d<5\ pC$	Upr	1 669	V_{peak}
Highest permissible overvoltage	Utr	8 000	V _{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	Tstg	-55 to +150	°C
Operating temperature range	Та	-55 to +100	°C
Isolation resistance, minimum value VIO = 500 V dc at TA = 25°C VIO = 500 V dc at TA MAX. at least 100°C	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I _F , Psi = 0) Power (output or total power dissipation) Isolation resistance	Tsi Isi Psi	175 400 700	°C mA mW
V _{IO} = 500 V dc at T _A = Tsi	Ris MIN.	10°	Ω

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GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

Revision History

PS2514-1,PS2514L-1 Data Sheet

		Description		
Rev.	Date	Page	Summary	
0.01	May 28, 2010	_	First edition issued	
1.00	Mar 19, 2012	Throughout	Preliminary Data Sheet -> Data Sheet	
		Throughout	Safety standards approved	
		p.1	Addition of Pb-Free product	
		p.3	Modification of MARKING EXAMPLE	
		p.4	Modification of ORDERING INFORMATION	
		pp.6 to 8	Addition of TYPICAL CHARACTERISTICS	
		p.10	Modification of RECOMMENDED MOUNT PAD DIMENSIONS	
		pp.11 to 12	Addition of NOTES ON HANDLING	
		p.13	Addition of SPECIFICATION OF VDE MARKS LICENSE DOCUMENT	